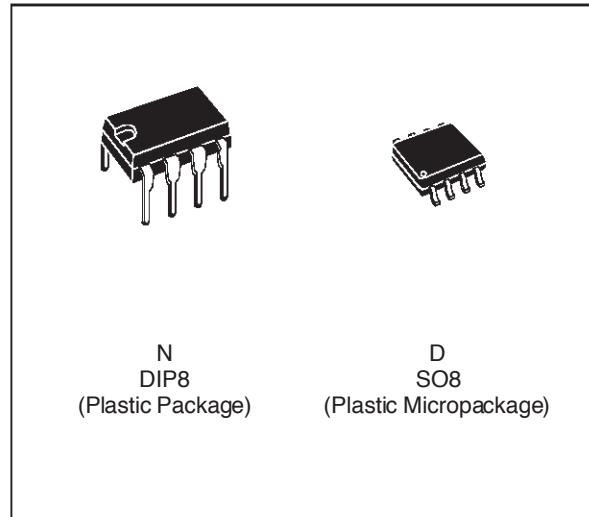




# TL081 TL081A - TL081B

## GENERAL PURPOSE J-FET SINGLE OPERATIONAL AMPLIFIER

- WIDE COMMON-MODE (UP TO  $V_{CC}^+$ ) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE : 16V/ $\mu$ s (typ)



### DESCRIPTION

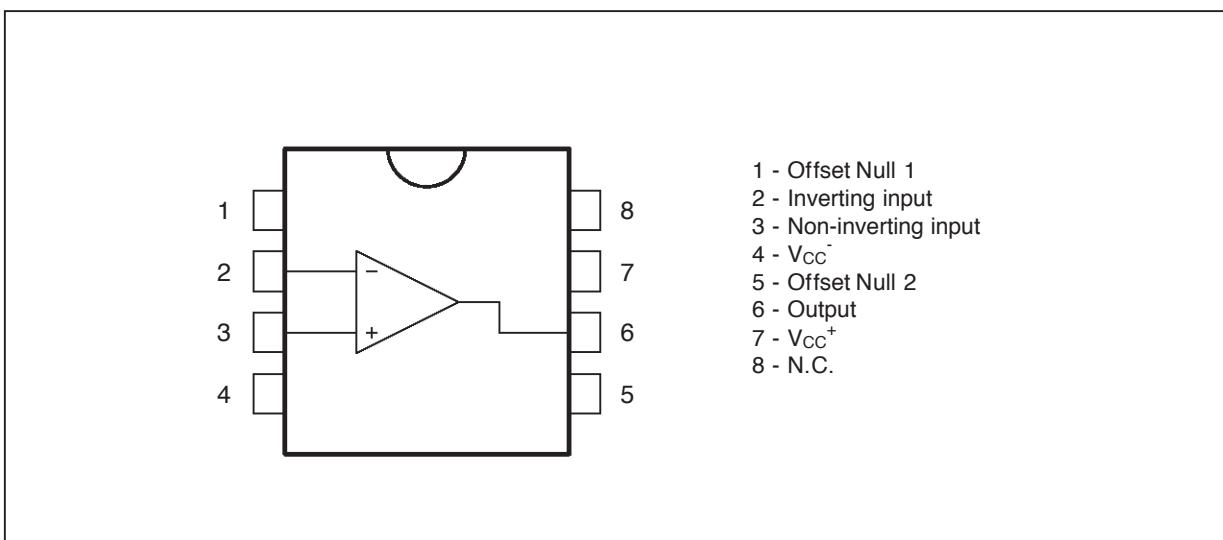
The TL081, TL081A and TL081B are high speed J-FET inputs single operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

### ORDER CODES

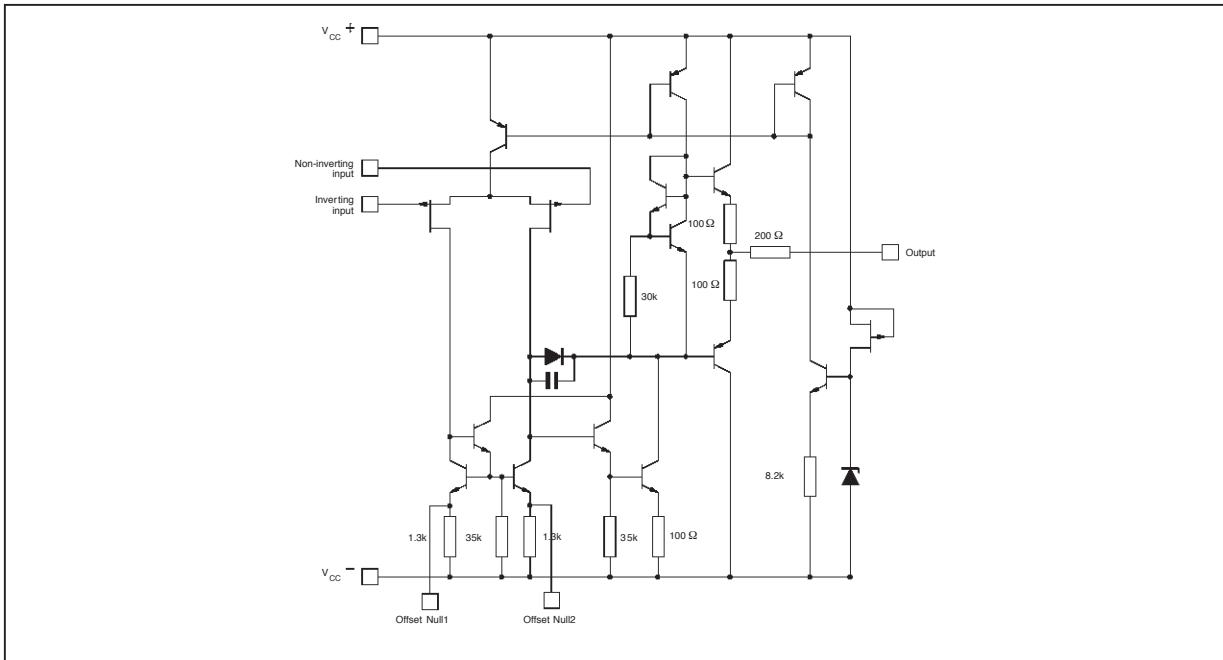
Part Number	Temperature Range	Package	
		N	D
TL081M/AM/BM	-55°C, +125°C	•	•
TL081I/AI/BI	-40°C, +105°C	•	•
TL081C/AC/BC	0°C, +70°C	•	•
Examples : TL081CD, TL081IN			

### PIN CONNECTIONS (top view)

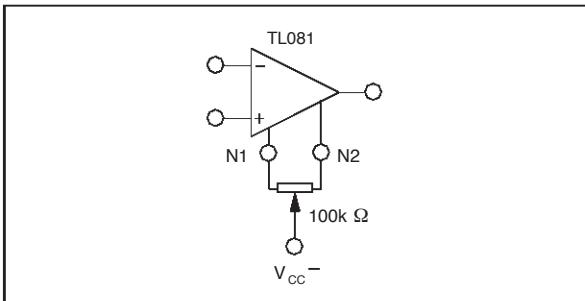


## TL081 - TL081A - TL081B

### SCHEMATIC DIAGRAM



### INPUT OFFSET VOLTAGE NULL CIRCUITS



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage - (note 1)	$\pm 18$	V
$V_i$	Input Voltage - (note 3)	$\pm 15$	V
$V_{id}$	Differential Input Voltage - (note 2)	$\pm 30$	V
$P_{tot}$	Power Dissipation	680	mW
	Output Short-circuit Duration - (note 4)	Infinite	
$T_{oper}$	Operating Free Air Temperature Range TL081C,AC,BC TL081I,AI,BI TL081M,AM,BM	0 to 70 -40 to 105 -55 to 125	°C
$T_{stg}$	Storage Temperature Range	-65 to 150	°C

Notes :

- All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between  $V_{CC}^+$  and  $V_{CC}^-$ .
- Differential voltages are at the non-inverting input terminal with respect to the inverting input terminal.
- The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
- The output may be shorted to ground or to either supply. Temperature and /or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

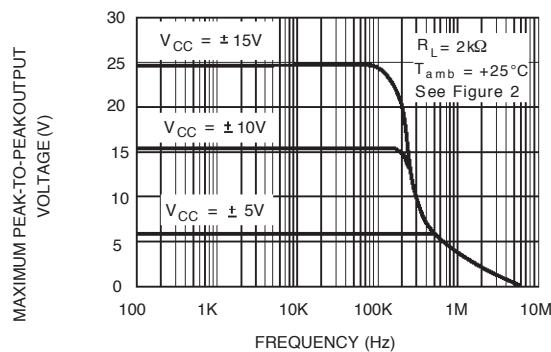
**ELECTRICAL CHARACTERISTICS** $V_{CC} = \pm 15V$ ,  $T_{amb} = 25^{\circ}C$  (unless otherwise specified)

Symbol	Parameter	TL081I,M,AC,AI, AM,BC,BI,BM			TL081C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
$V_{io}$	Input Offset Voltage ( $R_S = 50\Omega$ ) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	TL081 TL081A TL081B TL081 TL081A TL081B	3 3 1	10 6 3 13 7 5		3	10 13	mV
$DV_{io}$	Input Offset Voltage Drift		10			10		$\mu V/{\circ}C$
$I_{io}$	Input Offset Current * $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		5	100 4		5	100 4	pA nA
$I_{ib}$	Input Bias Current * $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		20	200 20		20	400 20	pA nA
$A_{vd}$	Large Signal Voltage Gain ( $R_L = 2k\Omega$ , $V_O = \pm 10V$ ) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio ( $R_S = 50\Omega$ ) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	80 80	86		70 70	86		dB
$I_{cc}$	Supply Current, no Load $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1.4	2.5 2.5		1.4	2.5 2.5	mA
$V_{icm}$	Input Common Mode Voltage Range	$\pm 11$	+15 -12		$\pm 11$	+15 -12		V
CMR	Common Mode Rejection Ratio ( $R_S = 50\Omega$ ) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	80 80	86		70 70	86		dB
$I_{os}$	Output Short-circuit Current $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	10 10	40	60 60	10 10	40	60 60	mA
$\pm V_{OPP}$	Output Voltage Swing $T_{amb} = 25^{\circ}C$ $R_L = 2k\Omega$ $R_L = 10k\Omega$ $T_{min.} \leq T_{amb} \leq T_{max.}$ $R_L = 2k\Omega$ $R_L = 10k\Omega$	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew Rate ( $V_{in} = 10V$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = 25^{\circ}C$ , unity gain)	8	16		8	16		V/ $\mu$ s
$t_r$	Rise Time ( $V_{in} = 20mV$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = 25^{\circ}C$ , unity gain)		0.1			0.1		$\mu$ s
Kov	Overshoot ( $V_{in} = 20mV$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = 25^{\circ}C$ , unity gain)		10			10		%
GBP	Gain Bandwidth Product ( $f = 100kHz$ , $T_{amb} = 25^{\circ}C$ , $V_{in} = 10mV$ , $R_L = 2k\Omega$ , $C_L = 100pF$ )	2.5	4		2.5	4		MHz
$R_i$	Input Resistance		$10^{12}$			$10^{12}$		$\Omega$
THD	Total Harmonic Distortion ( $f = 1kHz$ , $A_V = 20dB$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = 25^{\circ}C$ , $V_O = 2V_{PP}$ )		0.01			0.01		%
$e_n$	Equivalent Input Noise Voltage ( $f = 1kHz$ , $R_S = 100\Omega$ )		15			15		$\frac{nV}{\sqrt{Hz}}$
$\emptyset m$	Phase Margin		45			45		Degrees

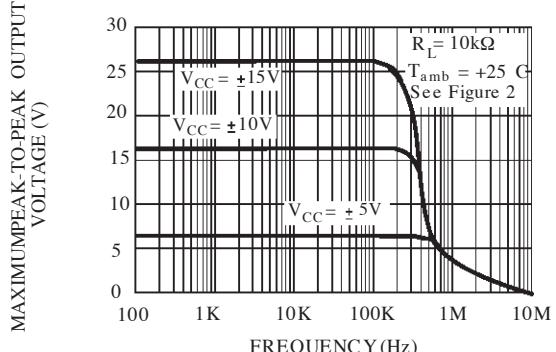
\* The input bias currents are junction leakage currents which approximately double for every  $10^{\circ}C$  increase in the junction temperature.

## TL081 - TL081A - TL081B

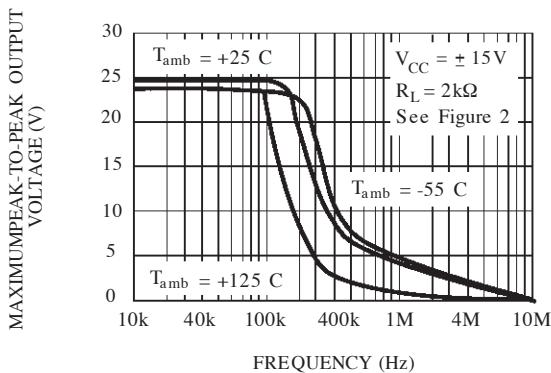
### MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREQUENCY



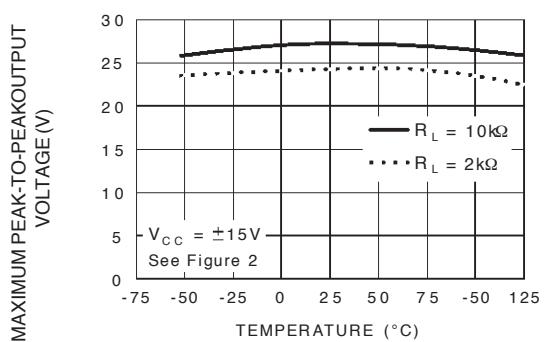
### MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREQUENCY



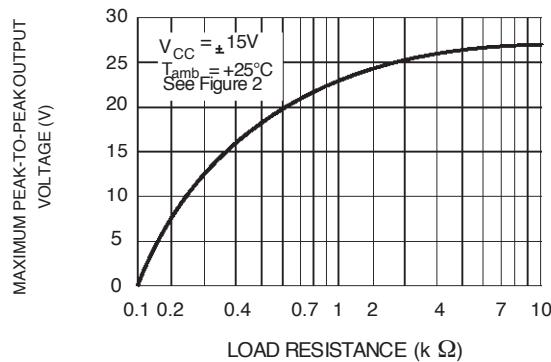
### MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREQUENCY



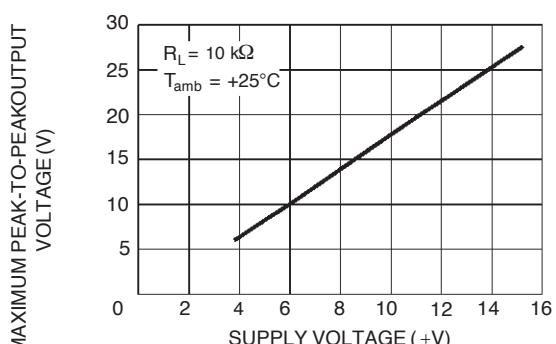
### MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREE AIR TEMP.



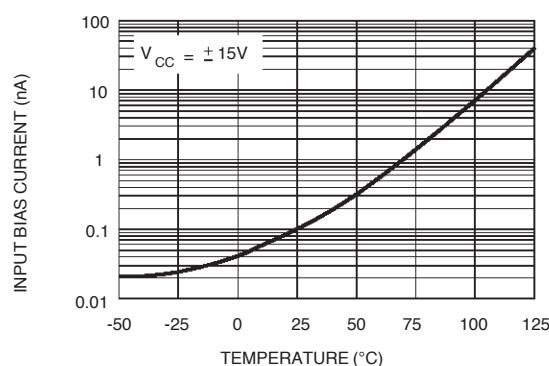
### MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS LOAD RESISTANCE



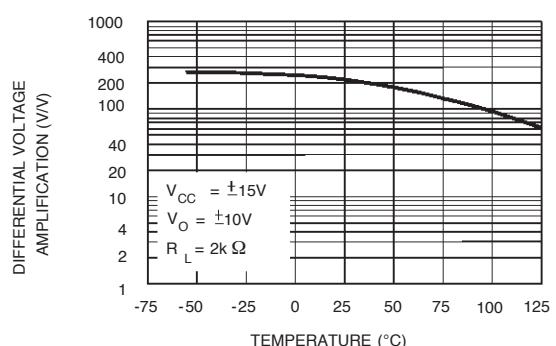
### MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS SUPPLY VOLTAGE



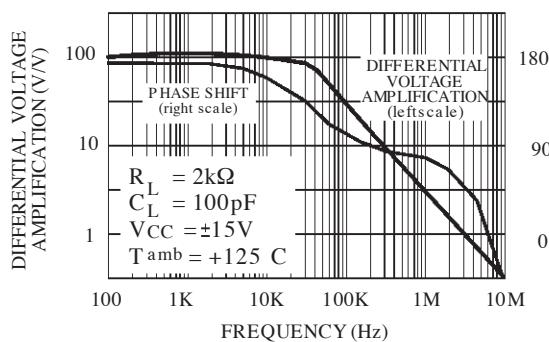
**INPUT BIAS CURRENT VERSUS  
FREE AIR TEMPERATURE**



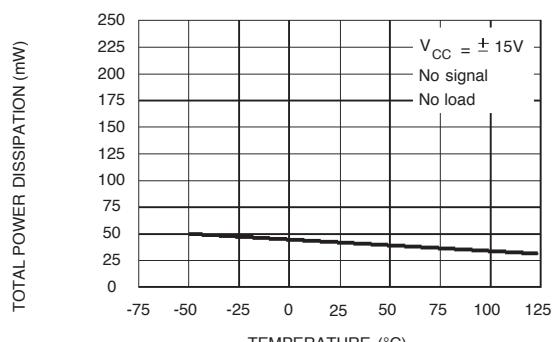
**LARGE SIGNAL DIFFERENTIAL  
VOLTAGE AMPLIFICATION VERSUS  
FREE AIR TEMPERATURE**



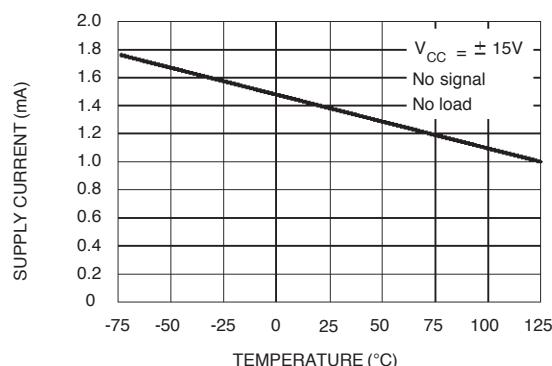
**LARGE SIGNAL DIFFERENTIAL  
VOLTAGE AMPLIFICATION AND PHASE  
SHIFT VERSUS FREQUENCY**



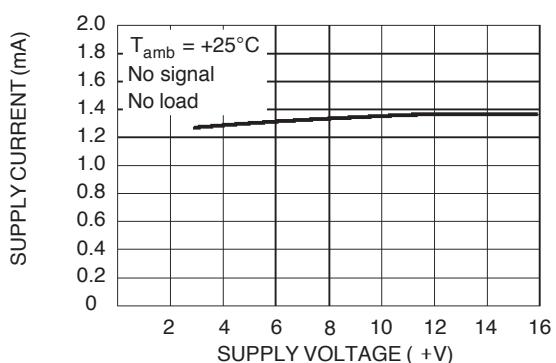
**TOTAL POWER DISSIPATION VERSUS  
FREE AIR TEMPERATURE**



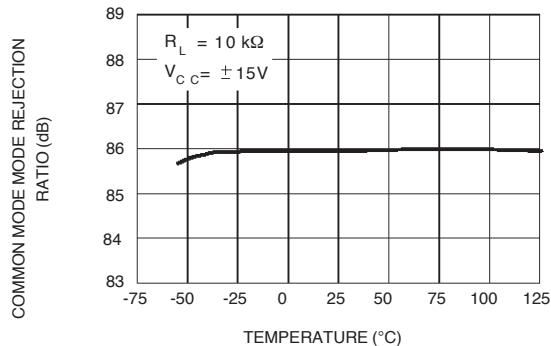
**SUPPLY CURRENT PER AMPLIFIER  
VERSUS FREE AIR TEMPERATURE**



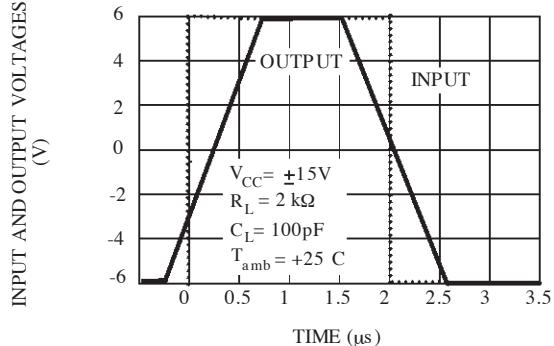
**SUPPLY CURRENT PER AMPLIFIER  
VERSUS SUPPLY VOLTAGE**



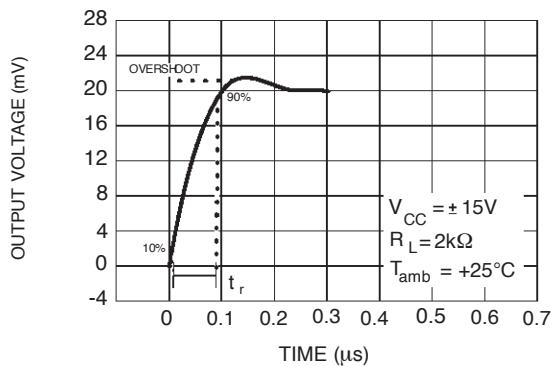
**COMMON MODE REJECTION RATIO  
VERSUS FREE AIR TEMPERATURE**



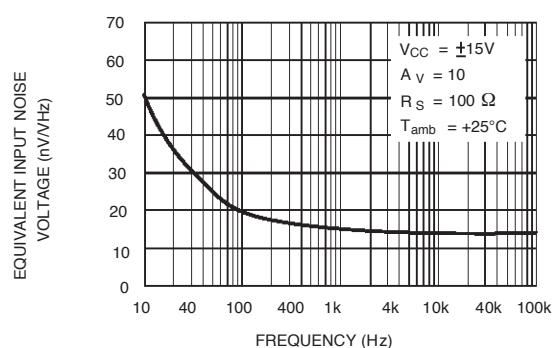
**VOLTAGE FOLLOWER LARGE SIGNAL  
PULSE RESPONSE**



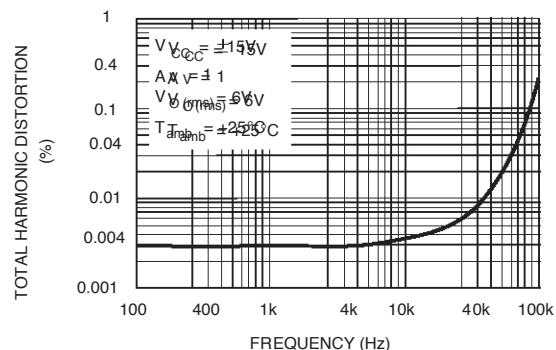
**OUTPUT VOLTAGE VERSUS  
ELAPSED TIME**



**EQUIVALENT INPUT NOISE VOLTAGE  
VERSUS FREQUENCY**



**TOTAL HARMONIC DISTORTION VERSUS  
FREQUENCY**



### PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

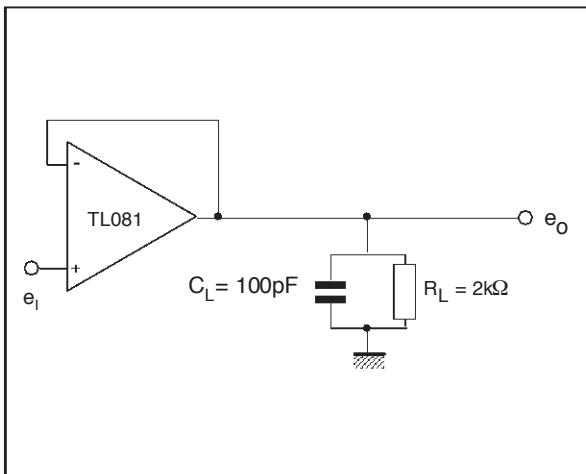
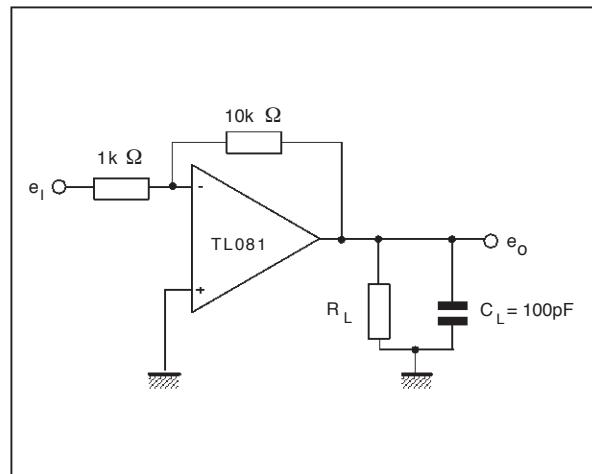
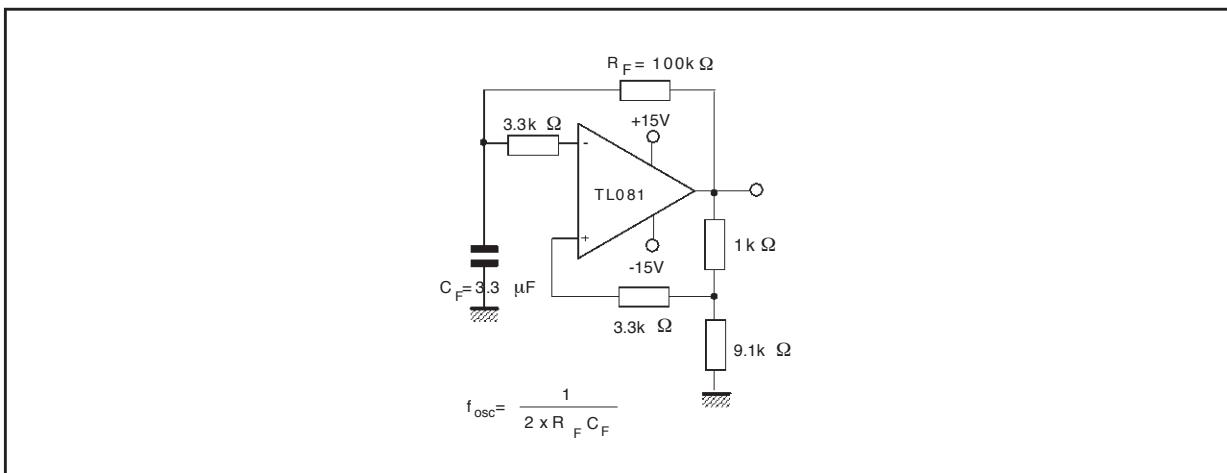


Figure 2 : Gain-of-10 Inverting Amplifier

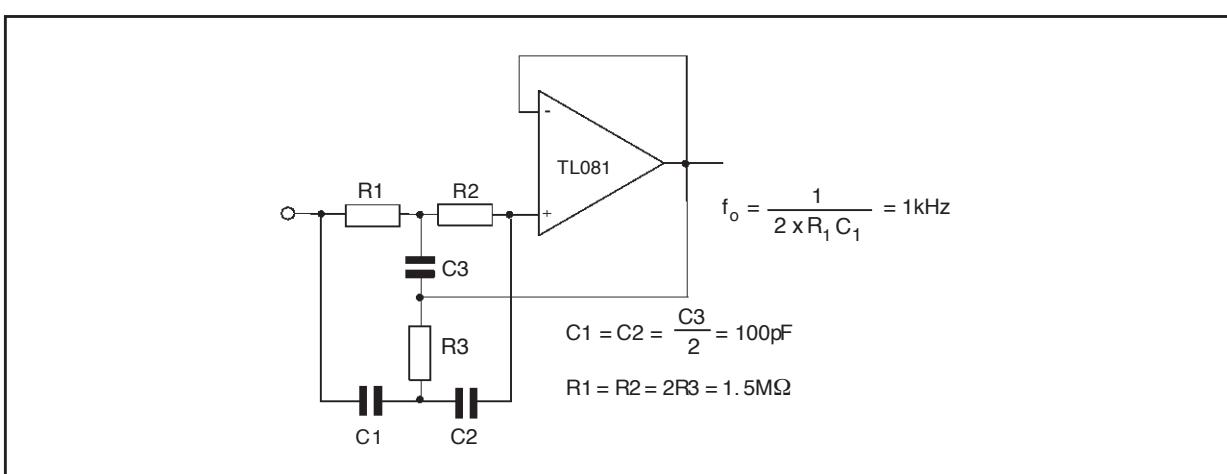


### TYPICAL APPLICATIONS

(0.5Hz) SQUARE WAVE OSCILLATOR



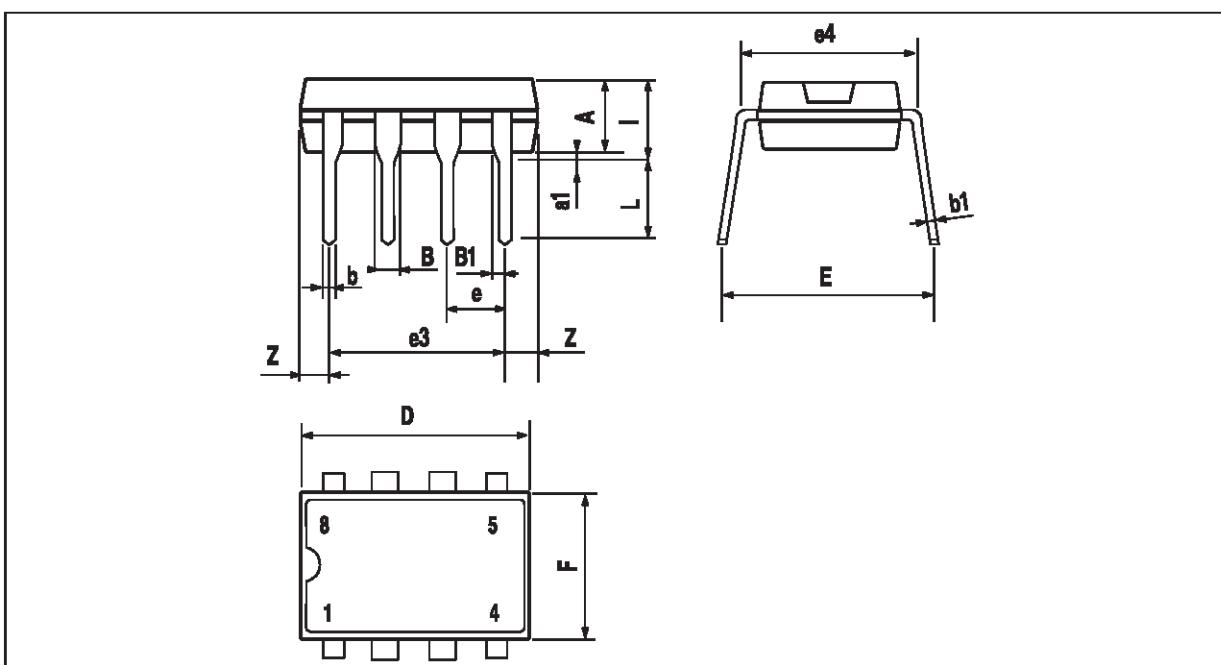
### HIGH Q NOTCH FILTER



## TL081 - TL081A - TL081B

### PACKAGE MECHANICAL DATA

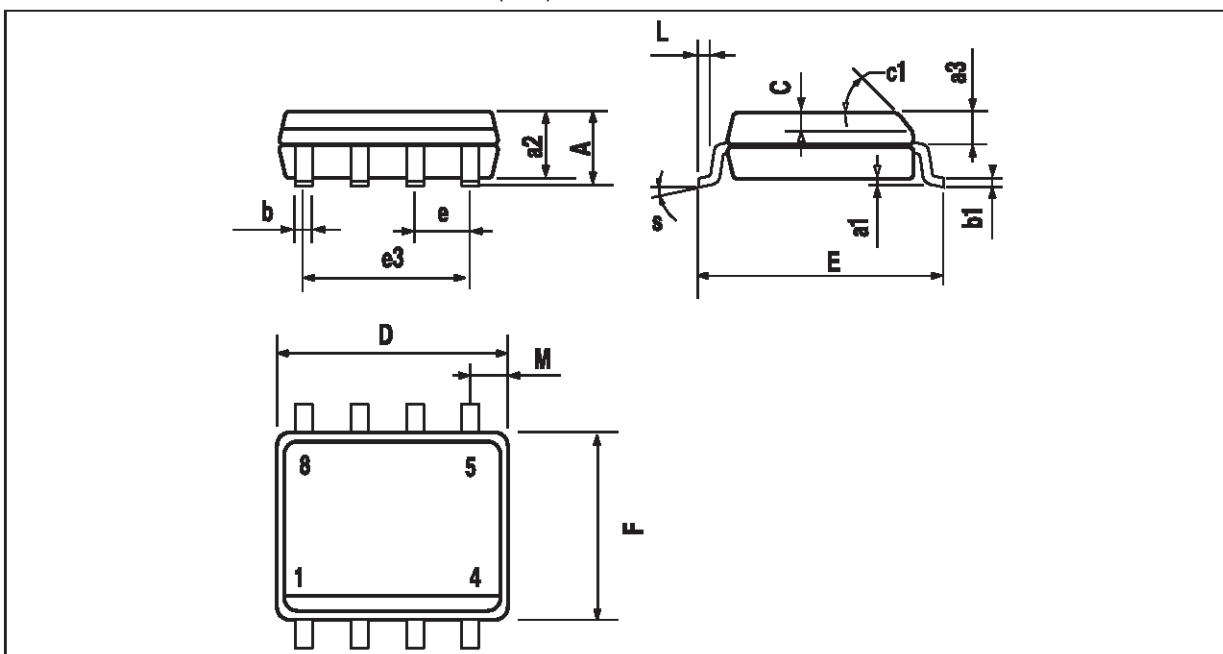
8 PINS - PLASTIC DIP



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

## PACKAGE MECHANICAL DATA

8 PINS - PLASTIC MICROPACKAGE (SO)



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a <sub>1</sub>	0.1		0.25	0.004		0.010
a <sub>2</sub>			1.65			0.065
a <sub>3</sub>	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b <sub>1</sub>	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c <sub>1</sub>	45° (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e <sub>3</sub>		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

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